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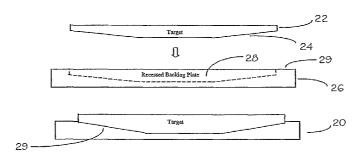
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Declarations under Rule 4.17:

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[Continued on next page]

(54) Title: EXTENDED LIFE SPUTTER TARGET



(57) Abstract: Provided is a method of manufacturing sputter target assemblies (20), and the products thereof. The method includes manufacturing a backing plate (26), the backing plate having a planar top surface and a cylindrical recess therein. Then a near final shape target insert (22) having a frusta-conical rear surface (24) that corresponds to the cylindrical recess (28) of the backing plate (26) and a front surface is manufactured. The target insert (22) has yield strength greater than that of the backing plate (26), and a height greater than the depth of the cylindrical recess in the backing plate (26). Thereafter, the target insert (22) is hot pressed into the cylindrical recess (28) of the backing plate (26) to a state of plastic deformation so as to diffusion bond the target insert (22) to the backing plate (26) and form the target assembly (20). The target insert (22) protrudes above the planar front surface of the backing plate (26).



WO 2005/026406 A1



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EXTENDED LIFE SPUTTER TARGET

Field of the Invention

[0001] This invention relates to the field of recessed sputter targets and particularly to a method of manufacturing recessed sputter targets.

Background of the Invention

In the field of sputter target manufacture, various means bond the target material to the backing plate. Historically, target manufacturers soldered targets to backing plates. With reference to Fig. 1, conventional sputtering target assemblies 10 are formed by bonding target insert 12 to backing plate 14. sputtering temperatures increased and target sizes increased, soldering failed to provide the necessary bond in view of the following disadvantages: 1) low melting temperatures limited chamber operating temperature; 2) the solder's high vapor pressure introduced impurities into the chamber; and 3) low bond strength, particularly at elevated temperatures, resulted in occasional bond failures. Since a debonded target can destroy not only a wafer, but also its supporting electrostatic chuck, it is most important to avoid bond failures. In fact, bond integrity is so important to sputter target manufacturers that Hunt et al., in US Pat. No. 6,092,427, developed a specialized method for preparing and testing bond interface evaluation samples. This method evaluates the strength of bonds between a sputter target and a backing plate. A sample of the material is removed through a first

- 2 -

opening formed at one end and a threaded opening formed to split the first opening into two openings.

Threading these openings and pulling the threaded openings measures the bond strength.

[0003] In view of the above problems, commercial target manufacturers have proposed several solutions for achieving a solid bond. For example, H. Zhang, in US Pat. No. 6,071,389, discloses the use of a titanium interlayer to diffusion bond a cobalt target to an aluminum or copper backing plate. The process deposits the titanium interlayer by electroplating, sputtering, electroless plating or plasma spraying. The deposited titanium bonds to both the cobalt and the backing plate material. This process also relies upon machining grooves into the target and backing plate to further improve bonding.

Hunt et al., in US Pat. Nos. 5,836,506 and [0004] 6,073,830 disclose a method for roughening a cylindrical target's back and side surfaces and diffusion bonding the target's back and side surfaces to a backing plate. This method forms a solid state bond and has proven most effective for securing a target to a backing plate. Unfortunately, since the target sputters preferentially from the center, the cylindrical target's yield or use during sputtering is far less than one-hundred percent. The low yields resulting from preferential center region sputtering leave an opportunity for improved target utilization. Thus, to develop sputter targets having improved yield and a requisite bond between the target insert and the backing plate, it is an object of the present invention to increase the sputter target

- 3 -

material utilization, thereby reducing overall costs associated with the frequent design, manufacturing and changes of the sputter target assembly in the sputtering apparatus.

[0006] It is another object of the invention, to provide a sputter target assembly, having a satisfactory configuration and meeting the overall requirements of the semiconductor industry.

[0007] It is a further object of the invention, to provide a satisfactory solid state bond between the target insert and the backing plate of similar and dissimilar materials.

[0008] Other objects and advantages of the present invention will become apparent to one of ordinary skill in the art upon review of the specification, drawings and appended claims.

Summary of the Invention

The foregoing objectives are met by the methods and apparatus of the present invention. accordance with a first aspect of the invention, a method of manufacturing a sputter target assembly is provided. The method includes manufacturing a backing plate, the backing plate having a planar top surface and a cylindrical recess therein. The recess has a depth and a diameter, and the backing plate has a yield Then a near final shape target insert is strength. manufactured. The target insert has a frusta-conical rear surface that corresponds to the cylindrical recess of the backing plate and a front surface. The target insert further has a yield strength greater than that of the backing plate, and a height greater than the

- 4 -

depth of the cylindrical recess in the backing plate. Thereafter, the target insert is hot pressed into the cylindrical recess of the backing plate to a state of plastic deformation so as to diffusion bond the target insert to the backing plate and form the target assembly. The target insert protrudes above the planar front surface of the backing plate.

[0010] In another aspect of the invention, a sputter target assembly is provided. The assembly includes a cylindrical backing plate having a planar front surface and a recess within the front surface and a target insert. The target insert has a height greater than the depth of the recess of the backing plate. The target insert has a front surface and a rear surface, the rear surface having at least about fifty percent of its surface area conical-shaped and the rear surface being bonded to the backing plate to secure the target insert to the backing plate. The recess is plastically deformed to the shape of the target insert, to form the target assembly and the target insert protrudes above the planar front surface of the backing plate.

[0011] In a further aspect of the invention, a sputter target assembly is provided. The assembly includes a cylindrical backing plate, the cylindrical backing plate having a planar front surface and a recess within the front surface and a target insert bonded to the backing plate within the recess of the backing plate. The target insert has a frusta-conical shaped front surface and a frusta-conical shaped rear surface, the rear surface having at least about sixty percent of its surface area conical-shaped and the rear surface being bonded to the backing plate to secure the

- 5 -

target insert to the backing plate. The recess is plastically deformed to the shape of the target insert, to form the target assembly.

Description of the Drawings

[0012] The objects and advantages of the invention will become apparent from the following detailed description of the preferred embodiments thereof in connection with the accompanying drawings, in which:

[0013] Figure 1 is a schematic drawing that illustrates the process for manufacturing a conventional sputtering target assembly.

[0014] Figure 2 is a schematic drawing that illustrates the process of manufacturing an extended life sputter target assembly.

[0015] Figure 3 is a schematic cross-section of the target assembly of Figure 2.

[0016] Figure 4 is a schematic drawing illustrating the process of manufacturing an extended life target target assembly in accordance with another embodiment.

Detailed Description of Preferred Embodiments Of the Invention

[0017] The invention provides a method for forming a sputter target assembly with a solid state bond. As illustrated in Figure 2, the process relies upon a target insert 22 having a conical-shaped rear surface 24 and a backing plate 26 having a partially mating cylindrical recess 28. Preferably the height of target insert 22 is higher than the depth of recess 28, thereby the target insert protrudes above planar surface 25 of backing plate 26. In this manner, the

- 6 -

overall thickness of the target is increased from about 20 to about 35 percent, while the sputter target material available to be utilized increases from about 50 to about 100 percent over related target assemblies.

[0018] During the formation of the sputter target assembly target, insert 22 is pressed into the cylindrical recess 28 and deforms backing plate 26 forming the target/backing plate assembly 20. In this step, the frusta-conical surface 24 maintains its shape and forms the bond. This bond secures the conical or frusta-conical backside 24 of target insert 22 to the backing plate 26. The sputter life of the target assembly is lengthened to between about 1,400 and about 1,600 kWh, while a conventional target assembly would have a sputter life between about 1,000 and about 1,200 kWh.

[0019] The manufacturing method of producing the taper or angled surface 29 may include but is not limited to machining, forging, pressing, casting, hot isostatic pressing (HIP) powder and spinning. Advantageously, the process includes pressing the target insert directly into its conical or partially conical shape to eliminate the material loss experienced by machining. The most suitable method depends upon the target material. Many target materials are suitable for hot pressing or even cold pressing the target into shape. This avoids the machining step and increases yield. High yields are essentially important for high cost target materials, such as high purity tungsten and tantalum. materials, pressing the target assembly directly into its insert shape is the most advantageous route for

- 7 -

producing the target. For these materials, this represents a clear cost and time savings over machining a tapered target insert to a surface corresponding to a tapered backing plate.

[0020] In addition, the use of high purity powders, such as tungsten powders, allows manufacturers to directly compress the powder directly into a target insert of near final shape.

[0021] Advantageously, maintaining the target insert and backing plate at a temperature of above 200°C for at least one hour during pressing improves bonding.

Most advantageously, pressing occurs at a temperature of at least 400 °C to further improve bonding between the rear surface of the target insert and the backing plate.

The backing plate 26 contains a cylindrical [0022] recess 28 formed by machining the backing plate. Most advantageously, ductile metals or alloys, such as aluminum, copper, aluminum-base alloys or copper-base alloys form the backing plate. Aluminum base alloys, such as alloy 6061 provide the necessary ductility. addition, the backing plate should have a yield strength less than the yield strength of the target material during pressing. Optionally, the backing plate recess 28 may contain square, tapered or rounded The recess 28 has a volume approximately corners. equal to the volume of the tapered insert 12. provides sufficient bonding without inducing excessive deformation of the backing plate. Advantageously, recess 28 has a volume that is at least ninety percent of the volume of tapered insert 22 to prevent excessive deformation during pressing of tapered insert 22 into

- 8 -

recess 28. Similarly, recess 28 advantageously has a volume of less than about one-hundred percent of the tapered insert 22 to allow sufficient pressing. Most advantageously, the recess 28 has a volume approximately equal to the tapered target insert's volume to limit stresses and maximize bonding.

[0023] Pressing the tapered target insert into the recess forms the target assembly. After pressing, the target material retains its original frusta-conical shape. This step relies upon hot pressing, such as vacuum hot pressing or a HIP process to form the final assembly. When the assembly is heated under pressure, the backing plate material reaches a state of plastic deformation that facilitates forming strong solid state bonds. High temperature pressing promotes the reaction of the target material with the backing plate. For some systems, i.e. a titanium target and an aluminum backing plate it is advantageous to diffuse and react the materials together to form reaction products that contribute to the bond strength.

[0024] After pressing, the target assembly is ready for finishing operations such as final target machining, polishing, cleaning and machining threaded mounting openings into the backing plate.

[0025] As illustrated in Figure 3, the target assembly 30 advantageously contains target insert 32 bonded along conical interface 34 and frustum interface 36 to backing plate 38. The frustum interface has a diameter D and the conical interface forms a ring of length L. The length L extends parallel to the frustum interface 36. The frustum interface 36 consists of at least about fifty percent of the bond surface area

- 9 -

between the target insert and the backing plate. Most advantageously, it consists of at least about sixty percent of the total bond surface area of the target insert. The target uses up to approximately about fifteen percent and as high as twenty percent less material to reduce manufacturing cost and achieve the same utilization and settings as a standard target assembly.

[0026] Figure 4 illustrates an alternate embodiment. The target insert 42 has a frusta-conical configuration of target assembly 40 on both the front and rear surfaces.

The bond interface does not lend itself to [0027] the use of mating machined grooves, since machined grooves could interfere with the plastic deformation of the backing plate. Advantageously however, a surface treatment step roughens the side and tapered surface of the target insert and the cylindrical recess to form an uneven surface topography to the surface to be bonded. Acceptable surface roughening techniques include, but are not limited to, particle blasting, shot peening and etching. Particles used in particle blasting can be selected from a group that may include but is not limited to: grit, sand, glass beads and steel shot. This process causes a subtle disruption of the associated bonding surface when the components are heated during pressing. Most advantageously, the process uses grit blasting to roughen the target insert to promote the formation of the desirable solid state bonding.

[0028] The near final shape target insert 42 has a frusta-conical rear shape which mates with backing

- 10 -

plate 48 along the aforementioned interface 50. In accordance with this embodiment, the near final shape target insert 42 has a tapered or angled front surface 44. The front surface is preferably frusta-conical. Additionally, target insert 42 has a yield strength greater than that of backing plate 48, and a height greater than the depth of the cylindrical recess in backing plate 48. As discussed above, the materials utilized for the backing plate and the target insert may be any one of the ones mentioned with respect to the previous embodiment. Upon pressing target insert 42 into backing plate 48 via a hot press process (e.g., vacuum hot pressing, HIP process) the backing plate material reaches a state of plastic deformation forming a strong bond therebetween. The final sputter target assembly has the target insert protruding above the planar surface 49 of backing plate 48. Accordingly, the sputter life of the target is increased to 2,400 kWh, as opposed to a conventional target assembly which provides a sputter life of about 1,000 to 1,200 kWh. The method and the sputter target assembly of the present invention will be further described in detail with reference to the following example which, however, shall not be construed as limiting the invention.

Example

[0029] A commercial 99.99 percent pure titanium disk having dimensions of 13.572" (34.5 cm) diameter x .750" (1.9 cm) thickness had a 3° angle machined on the rear bonding surface. The disk's rear bonding surface formed a cone-like shape. The titanium disk was placed in a cylindrical recess machined into a 6061-T6

aluminum disk. The recess contained a volume equal to the volume of the titanium target insert. A HIP process for 2 hours, at 15 ksi (103 MPa), at a temperature of 510 °C, bonded the insert to the backing plate. The aluminum disk became plastic during the HIP cycle and conformed to the shape of the tapered titanium target's 3° angle. The plastic deformation that occurred during the HIP process ensured a secure solid state bond. Evaluating this bond by ultrasonic testing, tensile testing and metallographic methods confirmed the bond integrity and strength.

[0030] Post HIP ultrasonic testing analysis revealed a one hundred percent bond between the backing plate and the target. In addition, the ultrasonic testing indicated a minor void in the area at the edge of the target.

[0031] Metallographic analysis revealed a consistent bond interface with one small void resulting from the square corner of the recessed backing plate not fully extruding or deforming. The location and size of this void would have no impact upon the target's performance. Furthermore, the bottom and side wall bond were equivalent to integral solid state bonding achieved with diffusion bonding techniques. In addition, subsequent testing has shown that a fillet located at the side wall of the recess eliminates any voids.

[0032] Two tensile tests in accordance with the two threaded opening sample method confirmed the excellent bond. Both samples, cut across the bond interface, had the aluminum fracture. The first sample fractured at

- 12 -

1,920 lbs. (13.2 MPa). The second sample fractured at 1,830 lbs. (12.6 MPa).

[0033] While an example is given for titanium targets, it is noteworthy that this process operates with similar effectiveness on sputter targets of any alloy or composition that is suitable for use as a sputter target such as, aluminum, titanium, copper, chromium, cobalt, nickel and tantalum. In addition, this process operates with the target material and backing plate being either similar or dissimilar alloys. For example, it is possible to place an aluminum-alloy target in an aluminum backing plate or in a copper backing plate.

[0034] The tapered target design uses a manufacturing-friendly process to recess the corresponding backing plate and easily adapts to various types of manufacturing equipment. The process also eliminates the need for special-cost-intensive machining of the backing plate blank and reduces the time required for manufacturing. Furthermore, it allows for the manufacture of a sputter target with a decreased thickness at its edges (typically 20 - 35%). Since this target assembly sputters preferentially from its center, this target requires no change in standard operating conditions. Optionally, the design increases the thickness of the target material without modification of a sputtering system's standard sputter procedure in comparison to a conventional cylindrical target insert. Furthermore, it increases sputter tool productivity by lowering the amount of target material required, thereby reducing cost. Finally, the process also facilitates the forming of strong vacuum

- 13 -

compatible bonds. These bonds can have more strength than the actual backing plate itself. Finally, the process reduces the design and manufacturing time required for new designs and products.

[0035] Many possible embodiments and sputter target configurations may be made of this invention without departing from the scope thereof, it is understood therefore that all matter set forth herein is to be interpreted as illustrative and not limiting in any manner.

- 14 -

PCT/US2004/027634

We claim:

WO 2005/026406

1. A method of manufacturing a sputter target assembly comprising the steps of:

- a) manufacturing a backing plate, the backing plate having a planar top surface and a cylindrical recess therein, the recess having a depth and a diameter, and the backing plate having a yield strength;
- b) manufacturing a near final shape target insert, wherein the target insert has a frusta-conical rear surface that corresponds to the cylindrical recess of the backing plate and a front surface, the target insert further having a yield strength greater than that of the backing plate, and a height greater than the depth of the cylindrical recess in the backing plate; and
- c) hot pressing the target insert into the cylindrical recess of the backing plate to a state of plastic deformation so as to diffusion bond the target insert to the backing plate and form the target assembly, where the target insert protrudes above the planar front surface of the backing plate.
- 2. The method of claim 1 wherein at least fifty percent of the frusta-conical rear surface bonds to the backing plate.
- 3. The method of claim 1 including the additional step of maintaining temperature of the target insert and backing plate above 200°C for at least one hour to improve bonding between the frusta-

- 15 -

conical rear surface of the target insert and the backing plate.

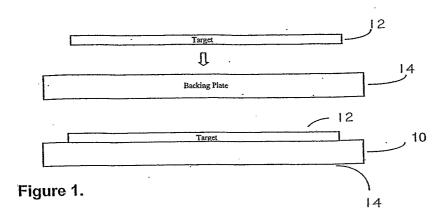
- 4. The method of claim 1 wherein the cylindrical recess has a volume and the target insert has a volume; and the cylindrical recess has a volume between about ninety and about one-hundred percent of the volume of the target insert.

recess within the front surface; and

- a target insert having a height greater than the depth of the recess of the backing plate, the target insert having a front surface and a rear surface, the rear surface having at least about fifty percent of its surface area conical-shaped and the rear surface being bonded to the backing plate to secure the target insert to the backing plate, wherein the recess is plastically deformed to the shape of the target insert, to form the target assembly and where the target insert protrudes above the planar front surface of the backing plate.
- 6. The sputter target of claim 5 wherein the recess has a shape conformed to the shape of the target insert.

- 16 -

- 7. The sputter target of claim 5 wherein a conical interface bonds the target insert to the backing plate.
- a target insert bonded to the backing plate within the recess of the backing plate, the target insert having a frusta-conical shaped front surface and a frusta-conical shaped rear surface, the rear surface having at least about sixty percent of its surface area conical-shaped and the rear surface being bonded to the backing plate to secure the target insert to the backing plate and form the target assembly, wherein the recess is plastically deformed to the shape of the target insert, to form the target assembly.
- 9. The sputter target of claim 8 wherein the recess has a shape conformed to the shape of the target insert.
- 10. The sputter target of claim 8 wherein the front surface of the target insert protrudes above the planar top surface of the backing plate.



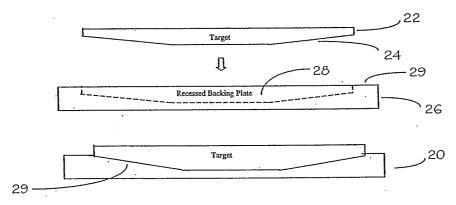


Figure 2.

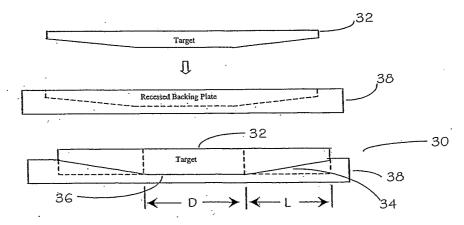


Figure 3.

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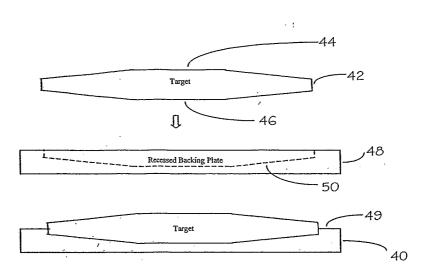


Figure 4.

INTERNATIONAL SEARCH REPORT

International application No.

PCT/US04/27634

A. CLASSIFICATION OF SUBJECT MATTER IPC(7): C23C 14/32; B23K 28/00 US CL: 204/298.12, 298.13; 228/164, 165, 193, 195 According to International Patent Classification (IPC) or to both national classification and IPC B. FIELDS SEARCHED Minimum documentation searched (classification system followed by classification symbols) U.S.: 204/298.12, 298.13; 228/164, 165, 193, 195			
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched NONE			
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) NONE			
C. DOCUMENTS CONSIDERED TO BE RELEVANT			
Category *	tegory * Citation of document, with indication, where appropriate, of the relevant passages		Relevant to claim No.
Y	US 6,599,405 A (HUNT et al) 29 July 2003 (29.07 66; Figure 1; Column 2 lines 30-31, lines 56-62; Column 6 lines 36-38, lines 42-44.	7.2003), Abstract; Column 1 lines 59- Column 3 lines 4-32, lines 49-53;	1-10
Y	US 5,674,367 A (HUNT et al) 07 October 1997, (07.10.1997), Column 3 lines 4-6; 1-10 Figure 7.		1-10
Further documents are listed in the continuation of Box C. See patent family annex.			
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